

Ref: ANRF/IRG/2024/000821/ENS

Date: 9th July 2025

Advertisement for the JRF Position in the ANRF Sponsored Project (ANRF/IRG/2024/000821/ENS)

Applications are invited from eligible candidates as a Junior Research Fellow (JRF) to work on the following project sponsored by ANRF **ANRF/IRG/2024/000821/ENS** under the supervision of Dr. Alok Kumar Kamal, **ABV-IIITM**, **Gwalior (An Autonomous Institute under MHRD, Govt. of India)**. The position is initially for **one year**, which may be extended for up to two additional years based on performance or till the completion of the project, whichever is earlier. The candidates can be enrolled in the Ph.D. program as per the institute norms. The details related to the project are as follows:

Project Th car and cry in pro acc	Advanced Biomedical Applications his project aims to develop a high-speed stochastic computational framework for simulating urier transport in nanostructured thermoelectric materials. By integrating hybrid Monte Carlo ad Boltzmann Transport models, it will address limitations of current methods in modelling non- ystalline materials. The framework will be optimized for biomedical applications, particularly fertility monitoring using temperature-sensitive thermoelectric sensors. The project will also oduce open-source tools, validated simulations, and potential patents, enabling scalable and curate material design for advanced biomedical devices.					
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pro	oduce open-source tools, validated simulations, and potential patents, enabling scalable and					
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nvestigator (PI) Dr	r. Alok Kumar Kamal					
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	Rs. 37000 + HRA (18%)					
	ostgraduate Degree (M.E./M.Tech./M.S.) in Electronics and Communication					
En	ngineering / Computer Science / Information Technology / Electrical Engineering					
or	related fields					
O	R					
Gi	Graduate Degree (B.E./B.Tech.) in the above disciplines with a valid GATE sco					
OI						
Po	ostgraduate Degree in Basic Sciences (such as Physics, Electronics, Computer					
	· · · · · · · · · · · · · · · · · · ·					
	Good knowledge of the fundamentals in semiconductor device physics and					
,	nanomaterials.					
•]	Proficiency in MATLAB and TCAD					
	5 th July 2025					
	nly shortlisted candidates will be informed by e-mail about the interview date. No					
Qualification	raduate Degree (B.E./B.Tech.) in the above disciplines with a valid GATE s R ostgraduate Degree in Basic Sciences (such as Physics, Electronics, Compu- cience) with a valid NET/GATE qualification Must have a mathematical background. Good knowledge of the fundamentals in semiconductor device physics and nanomaterials. Proficiency in MATLAB and TCAD 5 th July 2025					

Application Procedure:

- Candidates are requested to send their detailed CV, including their academic details with percentage/CGPA, research works/projects, and work experience (if any) along with application form (attached as Annexure I) to kamal@iiitm.ac.in with the subject line as "Application for the JRF position in the ANRF sponsored project (ANRF/IRG/2024/000821/ENS)."
- Only shortlisted candidates will be informed through email for an interview. The interview will be conducted in person in offline mode at ABV-IIITM Gwalior.

Notes:

- 1. The duration of the position extends for a maximum of three years. If the candidate performs unsatisfactory, the position can be terminated with 1-month notice.
- 2. Selected candidates can be enrolled in the Ph.D. program as per the institute's norms.

Dr. Alok Kumar Kamal (PI)

Assistant Professor ABV-Indian Institute of Information Technology and Management (ABV-IIITM), Gwalior, An autonomous Institute under MHRD, Govt. of India) NH-10, Morena Link Road, Gwalior-474015 (MP) India. Tel: +91-7007906489 email: kamal@iiitm.ac.in



ABV Indian Institute of Information Technology and Management Gwalior (An Institution of National Importance under MoE, Government of India) Morena Rd, IIITM Campus, Gwalior, Madhya Pradesh 474015

Application for the Post of Junior Research Fellow (JRF) in ANRF Sponsored Project Titled "High-Speed Stochastic Simulation Framework for Nanostructured Materials in Advanced Biomedical Applications" (Project No.: ANRF/IRG/2024/000821/ENS)

Applicant's Details:

1.	Name				РНОТО	
2.	Father's Name					
3.	Mother's Name					
4.	Male/Female					
5.	Address	Correspondence:		Permanent:		
6.	Contact Details	Email ID:		Phone Number:		
7.	Age:	Date of Birth:		Age as on the closing date of Advt:		
8.	Nationality:		Caste: GEN/SC/S	T/OBC (Attach supportin	g documents)	
9.	Languages Proficiency	Mother tongue:	0	ther languages:		

10. Educational Qualifications:

(Supporting documents should be submitted along with the application as a single PDF file)

Degree/Certific ate	Institute/University/Bo	ard/College	Year	Subject		Percentage/ CGPA	Class
10 th (10+2)							
Graduation							
Post Graduation							
GATE/NET (as applicable)	Details of GATE	Year:	I	Ra	ınk:		I
	Details of CSIR- UGC-NET	Year:		Sco	ore:		

Declaration: I hereby declare that the entries made in this application form are correct to the best of my knowledge and belief. I would also submit my latest CV along with this application.

Place:

Date:

(Signature of the applicant)